

March 1997

## Features

- **Low Operating Current**  
-  $V_{DD} = 5V$ , Cycle Time  $1\mu s$  ..... **8mA**
- **Industry Standard Pinout**
- **Two Chip-Select Inputs-Simple Memory Expansion**
- **Memory Retention for Standby Battery Voltage of 2V Minimum**
- **Output-Disable for Common I/O Systems**
- **Three-State Data Output for Bus-Oriented Systems**
- **Separate Data Inputs and Outputs**

## Ordering Information

| 5V         | 10V       | PACKAGE | TEMP. RANGE    | PKG. NO. |
|------------|-----------|---------|----------------|----------|
| CDP1822CE  | CDP1822E  | PDIP    | -40°C to +85°C | E22.4    |
| CDP1822CEX | CDP1822EX | Burn-In |                | E22.4    |
| CDP1822CD  | CDP1822D  | SBDIP   | -40°C to +85°C | D22.4A   |
| CDP1822CDX | -         | Burn-In |                | D22.4A   |

## Description

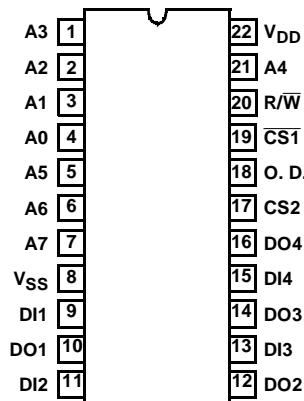
The CDP1822 and CDP1822C are 256-word by 4-bit static random-access memories designed for use in memory systems where high speed, low operating current, and simplicity in use are desirable. The CDP1822 features high speed and a wide operating voltage range. Both types have separate data inputs and outputs and utilize single power supplies of 4V to 6.5V for the CDP1822C and 4V to 10.5V for the CDP1822.

Two Chip-Select inputs are provided to simplify system expansion. An Output Disable control provides Wire-OR capability and is also useful in common Input/Output systems. The Output Disable input allows these RAMs to be used in common data Input/Output systems by forcing the output into a high-impedance state during a write operation independent of the Chip-Select input condition. The output assumes a high-impedance state when the Output Disable is at high level or when the chip is deselected by  $\overline{CS1}$  and/or  $\overline{CS2}$ .

The high noise immunity of the CMOS technology is preserved in this design. For TTL interfacing at 5V operation, excellent system noise margin is preserved by using an external pull-up resistor at each input.

## Pinout

CDP1822, CDP1822C  
(PDIP, SBDIP)  
TOP VIEW



OPERATIONAL MODES

| MODE           | INPUTS                             |                                    |                     |                  | OUTPUT         |
|----------------|------------------------------------|------------------------------------|---------------------|------------------|----------------|
|                | CHIP SELECT 1 ( $\overline{CS1}$ ) | CHIP SELECT 2 ( $\overline{CS2}$ ) | OUTPUT DISABLE (OD) | READ/WRITE (R/W) |                |
| Read           | 0                                  | 1                                  | 0                   | 1                | Read           |
| Write          | 0                                  | 1                                  | 0                   | 0                | Data In        |
| Write          | 0                                  | 1                                  | 1                   | 0                | High Impedance |
| Standby        | 1                                  | X                                  | X                   | X                | High Impedance |
| Standby        | X                                  | 0                                  | X                   | X                | High Impedance |
| Output Disable | X                                  | X                                  | 1                   | X                | High Impedance |

NOTE:

Logic 1 = High, Logic 0 = Low, X = Don't Care.

## CDP1822, CDP1822C

### Absolute Maximum Ratings

|   |                         |
|---|-------------------------|
| DC Supply Voltage Range, ( $V_{DD}$ )<br>(All Voltages Referenced to $V_{SS}$ Terminal) |                         |
| CDP1822   | -0.5V to +11V           |
| CDP1822C  | -0.5V to +7V            |
| Input Voltage Range, All Inputs   | -0.5V to $V_{DD}$ +0.5V |
| DC Input Current, Any One Input   | $\pm 10$ mA             |

### Thermal Information

|  |   |   |
|--|---|---|
| Thermal Resistance (Typical)   | $\theta_{JA}$ ( $^{\circ}\text{C}/\text{W}$ )           | $\theta_{JC}$ ( $^{\circ}\text{C}/\text{W}$ ) |
| PDIP Package   | 75  | N/A   |
| SBDIP Package  | 80  | 21  |
| Maximum Operating Temperature Range ( $T_A$ )                          |   |   |
| Package Type D   | -55 $^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$       |   |
| Package Type E   | -40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$        |   |
| Maximum Junction Temperature   |   |   |
| Ceramic Package  | 175 $^{\circ}\text{C}$                                  |   |
| Plastic Package  | 150 $^{\circ}\text{C}$                                  |   |
| Storage Temperature Range ( $T_{STG}$ )                                | -65 $^{\circ}\text{C}$ to +150 $^{\circ}\text{C}$       |   |
| $T_A = -40^{\circ}\text{C}$ to +60 $^{\circ}\text{C}$ (Package Type E) | 500mW   |   |
| $T_A = +60^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$ (Package Type E) | Derate Linearly at<br>12mW/ $^{\circ}\text{C}$ to 200mW |   |
| Lead Temperature (During Soldering)                                    | 300 $^{\circ}\text{C}$                                  |   |

**Recommended Operating Conditions** At  $T_A$  = Full Package Temperature Range. For maximum reliability, operating conditions should be selected so that operation is always within the following ranges:

| PARAMETER                  | SYMBOL | LIMITS   |          |          |          | UNITS |
|----------------------------|--------|----------|----------|----------|----------|-------|
|                            |        | CDP1822  |          | CDP1822C |          |       |
|                            |        | MIN      | MAX      | MIN      | MAX      |       |
| DC Operating Voltage Range |        | 4        | 10.5     | 4        | 6.5      | V     |
| Input Voltage Range        |        | $V_{SS}$ | $V_{DD}$ | $V_{SS}$ | $V_{DD}$ | V     |

**Static Electrical Specifications** At  $T_A = -40^{\circ}\text{C}$  to +85 $^{\circ}\text{C}$ , Except as Noted

| PARAMETER                    | SYMBOL   | CONDITIONS   |                 |                 | LIMITS  |                 |          |          |                 |         | UNITS         |
|------------------------------|----------|--------------|-----------------|-----------------|---------|-----------------|----------|----------|-----------------|---------|---------------|
|                              |          | $V_O$<br>(V) | $V_{IN}$<br>(V) | $V_{DD}$<br>(V) | CDP1822 |                 |          | CDP1822C |                 |         |               |
|                              |          |              |                 |                 | MIN     | (NOTE 1)<br>TYP | MAX      | MIN      | (NOTE 1)<br>TYP | MAX     |               |
| Quiescent Device Current     | $I_{DD}$ | -            | 0, 5            | 5               | -       | -               | 500      | -        | -               | 500     | $\mu\text{A}$ |
|                              |          | -            | 0, 10           | 10              | -       | -               | 1000     | -        | -               | -       | $\mu\text{A}$ |
| Output Low (Sink) Current    | $I_{OL}$ | 0.4          | 0, 5            | 5               | 2       | 4               | -        | 2        | 4               | -       | mA            |
|                              |          | 0.5          | 0, 10           | 10              | 4.5     | 9               | -        | -        | -               | -       | mA            |
| Output High (Source) Current | $I_{OH}$ | 4.6          | 0, 5            | 5               | -1      | -2              | -        | -1       | -2              | -       | mA            |
|                              |          | 9.5          | 0, 10           | 10              | -2.2    | -4.4            | -        | -        | -               | -       | mA            |
| Output Voltage Low-Level     | $V_{OL}$ | -            | 0, 5            | 5               | -       | 0               | 0.1      | -        | 0               | 0.1     | V             |
|                              |          | -            | 0, 10           | 10              | -       | 0               | 0.1      | -        | -               | -       | V             |
| Output Voltage High-Level    | $V_{OH}$ | -            | 0, 5            | 5               | 4.9     | 5               | -        | 4.9      | 5               | -       | V             |
|                              |          | -            | 0, 10           | 10              | 9.9     | 10              | -        | -        | -               | -       | V             |
| Input Low Voltage            | $V_{IL}$ | 0.5, 4.5     | -               | 5               | -       | -               | 1.5      | -        | -               | 1.5     | V             |
|                              |          | 0.5, 9.5     | -               | 10              | -       | -               | 3        | -        | -               | -       | V             |
| Input High Voltage           | $V_{IH}$ | 0.5, 9.5     | -               | 5               | 3.5     | -               | -        | 3.5      | -               | -       | V             |
|                              |          | 0.5, 9.5     | -               | 10              | 7       | -               | -        | -        | -               | -       | V             |
| Input Leakage Current        | $I_{IN}$ | -            | 0, 5            | 5               | -       | -               | $\pm 5$  | -        | -               | $\pm 5$ | $\mu\text{A}$ |
|                              |          | -            | 0, 10           | 10              | -       | -               | $\pm 10$ | -        | -               | -       | $\mu\text{A}$ |

## CDP1822, CDP1822C

### Static Electrical Specifications At $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ , Except as Noted (Continued)

| PARAMETER                             | SYMBOL    | CONDITIONS   |                 |                 | LIMITS  |                 |          |          |                 |         | UNITS         |
|---------------------------------------|-----------|--------------|-----------------|-----------------|---------|-----------------|----------|----------|-----------------|---------|---------------|
|                                       |           | $V_O$<br>(V) | $V_{IN}$<br>(V) | $V_{DD}$<br>(V) | CDP1822 |                 |          | CDP1822C |                 |         |               |
|                                       |           |              |                 |                 | MIN     | (NOTE 1)<br>TYP | MAX      | MIN      | (NOTE 1)<br>TYP | MAX     |               |
| Operating Current<br>(Note 2)         | $I_{DD1}$ | -            | 0, 5            | 5               | -       | 4               | 8        | -        | 4               | 8       | mA            |
|                                       |           | -            | 0, 10           | 10              | -       | 8               | 16       | -        | -               | -       | mA            |
| Three-State Output<br>Leakage Current | $I_{OUT}$ | 0, 5         | 0, 5            | 5               | -       | -               | $\pm 5$  | -        | -               | $\pm 5$ | $\mu\text{A}$ |
|                                       |           | 0, 10        | 0, 10           | 10              | -       | -               | $\pm 10$ | -        | -               | -       | $\mu\text{A}$ |
| Input Capacitance                     | $C_{IN}$  | -            | -               | -               | -       | 5               | 7.5      | -        | 5               | 7.5     | pF            |
| Output Capacitance                    | $C_{OUT}$ | -            | -               | -               | -       | 10              | 15       | -        | 10              | 15      | pF            |

#### NOTES:

- Typical values are for  $T_A = +25^{\circ}\text{C}$  and nominal  $V_{DD}$ .
- Outputs open circuited; Cycle time =  $1\mu\text{s}$ .

### Dynamic Electrical Specifications At $T_A = -40$ to $+85^{\circ}\text{C}$ , $V_{DD} \pm 5\%$ , Input $t_R, t_F = 20\text{ns}$ , $V_{IH} = 0.7 V_{DD}$ , $V_{IL} = 0.3 V_{DD}$ , $C_L = 100\text{pF}$

| PARAMETER   | TEST<br>CONDITIONS | LIMITS          |                 |                 |     |                 |                 |     | UNITS |
|---|--------------------|-----------------|-----------------|-----------------|-----|-----------------|-----------------|-----|-------|
|   |                    | $V_{DD}$<br>(V) | CD1822          |                 |     | CDP1822C        |                 |     |       |
|   |                    |                 | (NOTE 1)<br>MIN | (NOTE 2)<br>TYP | MAX | (NOTE 1)<br>MIN | (NOTE 2)<br>TYP | MAX |       |
| Read Cycle Times (Figure 1)                         |                    |                 |                 |                 |     |                 |                 |     |       |
| Read Cycle  | $t_{RC}$           | 5               | 450             | -               | -   | 450             | -               | -   | ns    |
|   |                    | 10              | 250             | -               | -   | -               | -               | -   | ns    |
| Access from Address                                 | $t_{AA}$           | 5               | -               | 250             | 450 | -               | 250             | 450 | ns    |
|   |                    | 10              | -               | 150             | 250 | -               | -               | -   | ns    |
| Output Valid from $\overline{\text{Chip-Select}} 1$ | $t_{DOA1}$         | 5               | -               | 250             | 450 | -               | 250             | 450 | ns    |
|   |                    | 10              | -               | 150             | 250 | -               | -               | -   | ns    |
| Output Valid from Chip-Select 2                     | $t_{DOA2}$         | 5               | -               | 250             | 450 | -               | 250             | 450 | ns    |
|   |                    | 10              | -               | 150             | 250 | -               | -               | -   | ns    |
| Output Valid from Output Disable                    | $t_{DOA3}$         | 5               | -               | -               | 200 | -               | -               | 200 | ns    |
|   |                    | 10              | -               | -               | 110 | -               | -               | -   | ns    |
| Output Hold from $\overline{\text{Chip-Select}} 1$  | $t_{DOH1}$         | 5               | 20              | -               | -   | 20              | -               | -   | ns    |
|   |                    | 10              | 20              | -               | -   | -               | -               | -   | ns    |
| Output Hold from Chip-Select 2                      | $t_{DOH2}$         | 5               | 20              | -               | -   | 20              | -               | -   | ns    |
|   |                    | 10              | 20              | -               | -   | -               | -               | -   | ns    |
| Output Hold from Output Disable                     | $t_{DOH3}$         | 5               | 20              | -               | -   | 20              | -               | -   | ns    |
|   |                    | 10              | 20              | -               | -   | -               | -               | -   | ns    |

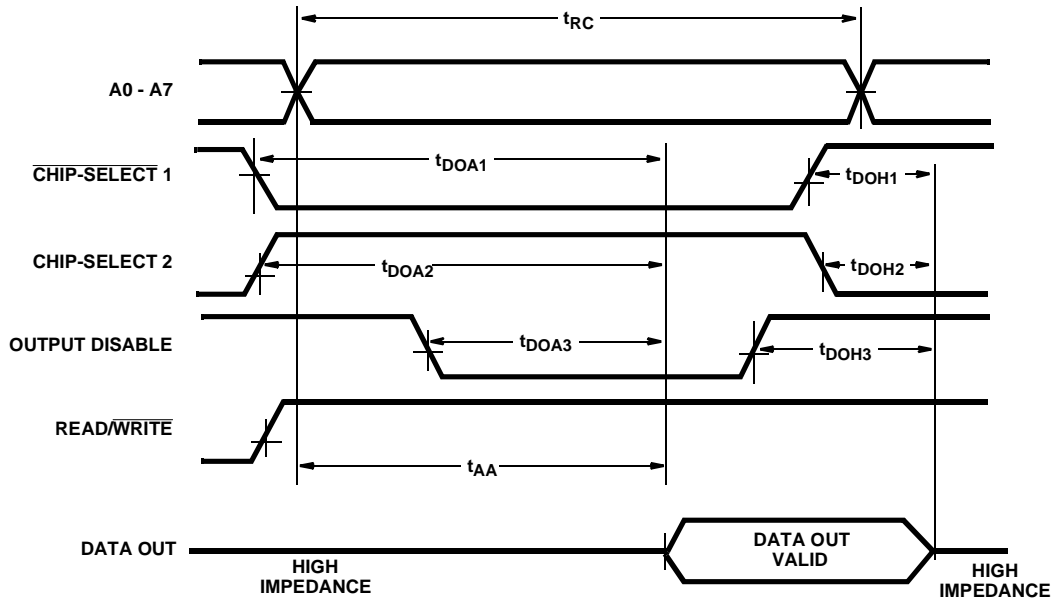
## CDP1822, CDP1822C

**Dynamic Electrical Specifications** At  $T_A + -40$  to  $+85^\circ\text{C}$ ,  $V_{DD} \pm 5\%$ , Input  $t_R, t_F = 20\text{ns}$ ,  $V_{IH} = 0.7 V_{DD}$ ,  $V_{IL} = 0.3 V_{DD}$ ,  $C_L = 100 \text{pF}$  (Continued)

| PARAMETER | TEST CONDITIONS | LIMITS       |              |     |              |              |     | UNITS |
|-----------|-----------------|--------------|--------------|-----|--------------|--------------|-----|-------|
|           | $V_{DD}$ (V)    | CD1822       |              |     | CDP1822C     |              |     |       |
|           |                 | (NOTE 1) MIN | (NOTE 2) TYP | MAX | (NOTE 1) MIN | (NOTE 2) TYP | MAX |       |

NOTES:

1. Time required by a limit device to allow for indicated function.
2. Typical values are for  $T_A = 25^\circ\text{C}$  and nominal  $V_{DD}$ .



**FIGURE 1. READ CYCLE TIMING WAVEFORMS**

**Dynamic Electrical Specifications** At  $T_A + -40$  to  $+85^\circ\text{C}$ ,  $V_{DD} \pm 5\%$ , Input  $t_R, t_F = 20\text{ns}$ ,  $V_{IH} = 0.7 V_{DD}$ ,  $V_{IL} = 0.3 V_{DD}$ ,  $C_L = 100 \text{pF}$ .

| PARAMETER                   | TEST CONDITIONS | LIMITS       |              |     |              |              |     | UNITS |    |
|-----------------------------|-----------------|--------------|--------------|-----|--------------|--------------|-----|-------|----|
|                             |                 | CD1822       |              |     | CDP1822C     |              |     |       |    |
|                             |                 | (NOTE 1) MIN | (NOTE 2) TYP | MAX | (NOTE 1) MIN | (NOTE 2) TYP | MAX |       |    |
| Read Cycle Times (Figure 2) |                 |              |              |     |              |              |     |       |    |
| Write Cycle                 | $t_{WC}$        | 5            | 500          | -   | -            | 500          | -   | -     | ns |
|                             |                 | 10           | 300          | -   | -            | -            | -   | -     | ns |
| Address Setup               | $t_{AS}$        | 5            | 200          | -   | -            | 200          | -   | -     | ns |
|                             |                 | 10           | 110          | -   | -            | -            | -   | -     | ns |
| Write Recovery              | $t_{WR}$        | 5            | 50           | -   | -            | 50           | -   | -     | ns |
|                             |                 | 10           | 40           | -   | -            | -            | -   | -     | ns |
| Write Width                 | $t_{WRW}$       | 5            | 250          | -   | -            | 250          | -   | -     | ns |
|                             |                 | 10           | 150          | -   | -            | -            | -   | -     | ns |

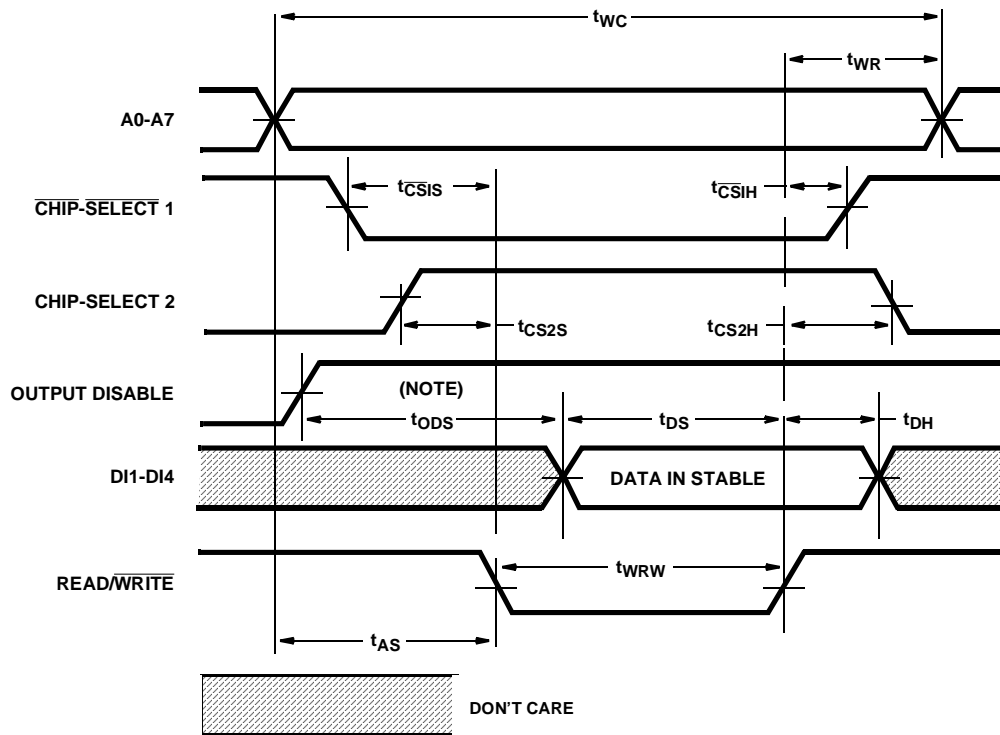
## CDP1822, CDP1822C

**Dynamic Electrical Specifications** At  $T_A + -40$  to  $+85^\circ\text{C}$ ,  $V_{DD} \pm 5\%$ , Input  $t_R, t_F = 20\text{ns}$ ,  $V_{IH} = 0.7 V_{DD}$ ,  $V_{IL} = 0.3 V_{DD}$ ,  $C_L = 100 \text{pF}$ . **(Continued)**

| PARAMETER                       | TEST CONDITIONS | LIMITS          |                 |     |                 |                 |     | UNITS |
|---------------------------------|-----------------|-----------------|-----------------|-----|-----------------|-----------------|-----|-------|
|                                 |                 | CD1822          |                 |     | CDP1822C        |                 |     |       |
|                                 |                 | (NOTE 1)<br>MIN | (NOTE 2)<br>TYP | MAX | (NOTE 1)<br>MIN | (NOTE 2)<br>TYP | MAX |       |
| Input Data Setup Time $t_{DS}$  | 5               | 250             | -               | -   | 250             | -               | -   | ns    |
|                                 | 10              | 150             | -               | -   | -               | -               | -   | ns    |
| Data Hold $t_{DH}$              | 5               | 50              | -               | -   | 50              | -               | -   | ns    |
|                                 | 10              | 40              | -               | -   | -               | -               | -   | ns    |
| Chip-Select 1 Setup $t_{CS1S}$  | 5               | 200             | -               | -   | 200             | -               | -   | ns    |
|                                 | 10              | 110             | -               | -   | -               | -               | -   | ns    |
| Chip-Select 2 Setup $t_{CS2S}$  | 5               | 200             | -               | -   | 200             | -               | -   | ns    |
|                                 | 10              | 110             | -               | -   | -               | -               | -   | ns    |
| Chip-Select 1 Hold $t_{CS1H}$   | 5               | 0               | -               | -   | 0               | -               | -   | ns    |
|                                 | 10              | 0               | -               | -   | 0               | -               | -   | ns    |
| Chip-Select 2 Hold $t_{CS2H}$   | 5               | 0               | -               | -   | 0               | -               | -   | ns    |
|                                 | 10              | 0               | -               | -   | 0               | -               | -   | ns    |
| Output Disable Set-Up $t_{ODS}$ | 5               | 200             | -               | -   | 200             | -               | -   | ns    |
|                                 | 10              | 110             | -               | -   | -               | -               | -   | ns    |

**NOTES:**

1. Time required by a limit device to allow for indicated function.
2. Typical values are for  $T_A = 25^\circ\text{C}$  and nominal  $V_{DD}$ .



NOTE:  $t_{ODS}$  is required for common I/O operation only. For separate I/O operations, output disable is don't care.

**FIGURE 2. WRITE CYCLE TIME WAVEFORMS**

## CDP1822, CDP1822C

**Data Retention Specifications** At  $T_A = -40$  to  $+85^\circ\text{C}$ , see Figure 3.

| PARAMETER                               | TEST CONDITIONS | LIMITS          |                 |     |                 |     |     |                 | UNITS |               |
|---|-----------------|-----------------|-----------------|-----|-----------------|-----|-----|-----------------|-------|---------------|
|   |                 | CDP1822         |                 |     | CDP1822C        |     |     |                 |       |               |
|   |                 | $V_{DR}$<br>(V) | $V_{DD}$<br>(V) | MIN | (NOTE 1)<br>TYP | MAX | MIN | (NOTE 1)<br>TYP |       | MAX           |
| Min. Data Retention Voltage             | $V_{DR}$        | -               | -               | -   | 1.5             | 2   | -   | 1.5             | 2     | V             |
| Data Retention Quiescent Current        | $I_{DD}$        | 2               | -               | -   | 30              | 100 | -   | 30              | 100   | $\mu\text{A}$ |
| Chip Deselect to Data Retention Time    | $t_{CDR}$       | -               | 5               | 600 | -               | -   | 600 | -               | -     | ns            |
|   |                 | -               | 10              | 300 | -               | -   | -   | -               | -     | ns            |
| Recovery to Normal Operation Time       | $t_{RC}$        | -               | 5               | 600 | -               | -   | 600 | -               | -     | ns            |
|   |                 | -               | 10              | 300 | -               | -   | -   | -               | -     | ns            |
| $V_{DD}$ to $V_{DR}$ Rise and Fall Time | $t_R, t_F$      | 2               | 5               | 1   | -               | -   | 1   | -               | -     | $\mu\text{A}$ |

NOTE: Typical values are for  $T_A = 25^\circ\text{C}$  and nominal  $V_{DD}$ .

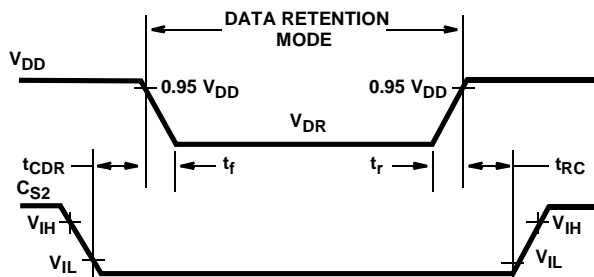


FIGURE 3. LOW  $V_{DD}$  DATA RETENTION TIME WAVEFORMS

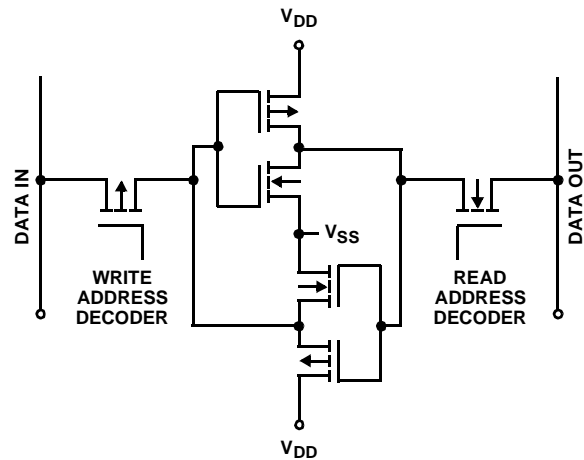
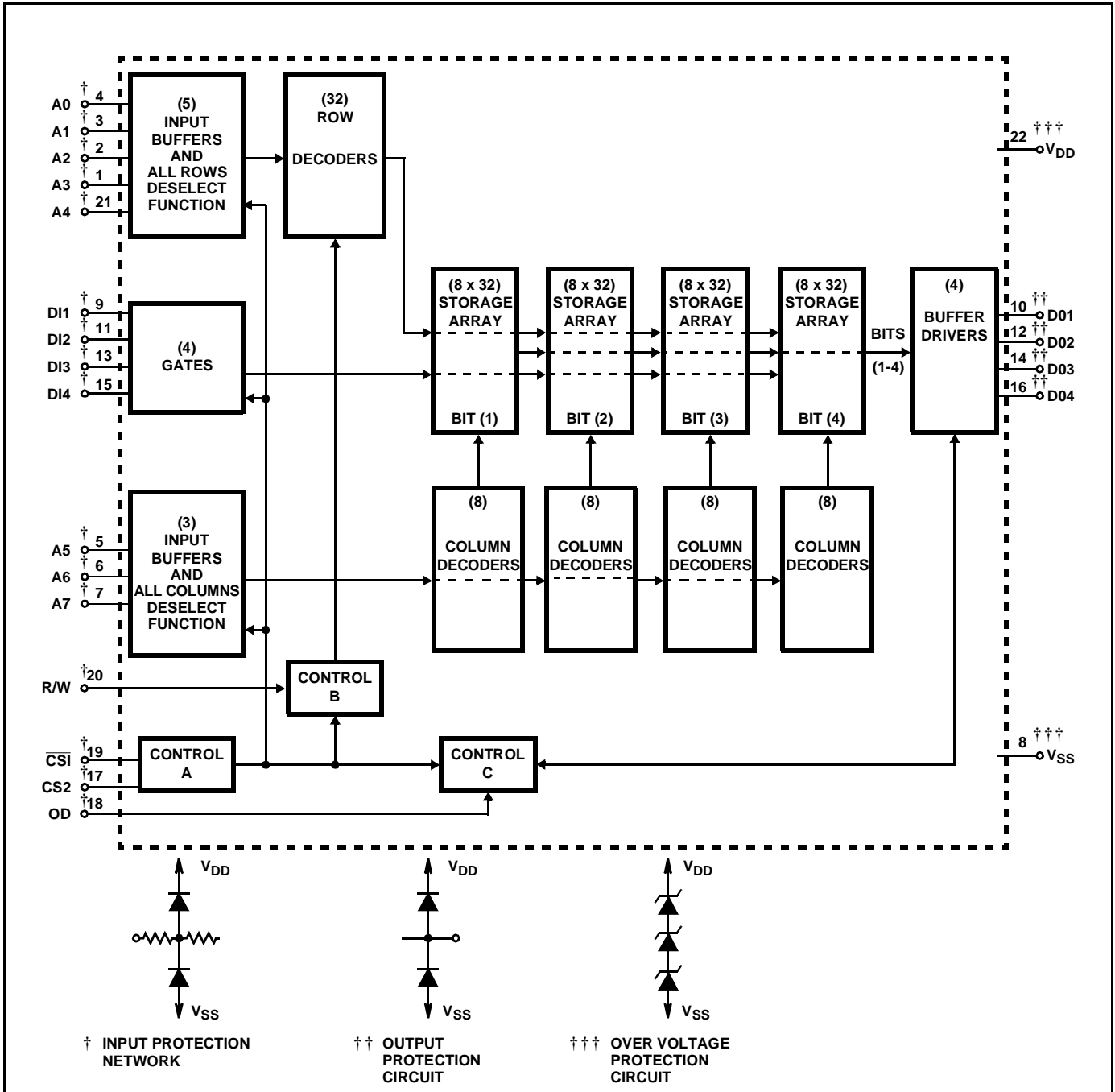


FIGURE 4. MEMORY CELL CONFIGURATION

# CDP1822, CDP1822CS



† INPUT PROTECTION NETWORK  
 †† OUTPUT PROTECTION CIRCUIT  
 ††† OVER VOLTAGE PROTECTION CIRCUIT

**FIGURE 5. FUNCTIONAL BLOCK DIAGRAM FOR CDP1822 AND CDP1822CS**  
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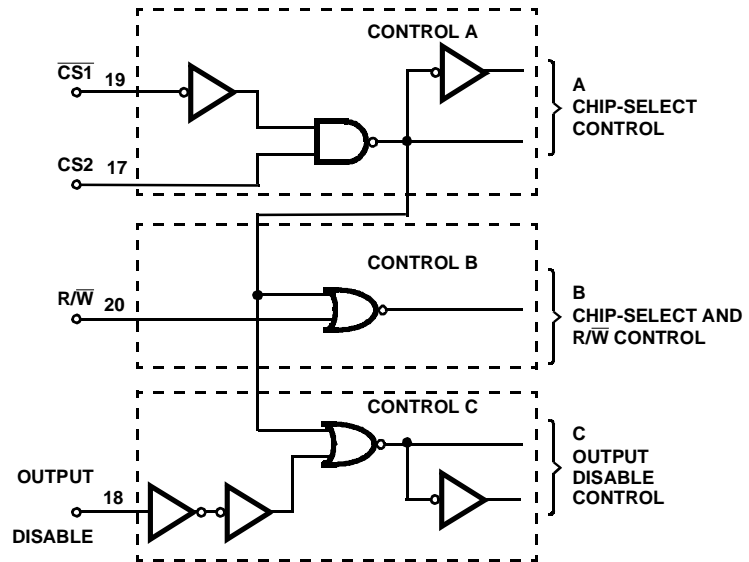


FIGURE 6. LOGIC DIAGRAM OF CONTROLS FOR CDP1822 AND CDP1822C